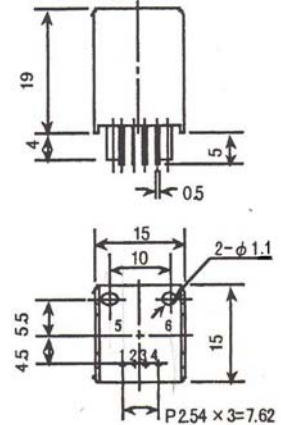
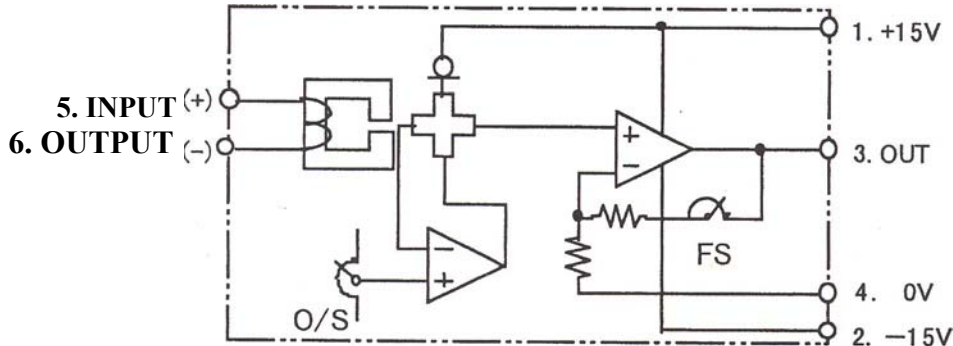


Subminiature DC Current Hall Amp Sensor HPS-25-AP

1. Circuit Diagram/Outward Dimensions:



2. Assembly parts / Standard:

Part	Material	Hard-flammability Standard
Case	PBT resin(20% of glass contained)	UL94 V-0
Bobbin	PBT resin(20% of grass contained)	UL94 V-0
Core	Permalloy	-----
Winding	2UEW-Φ1.8	-----
Hall element	GaAs Hall element	-----

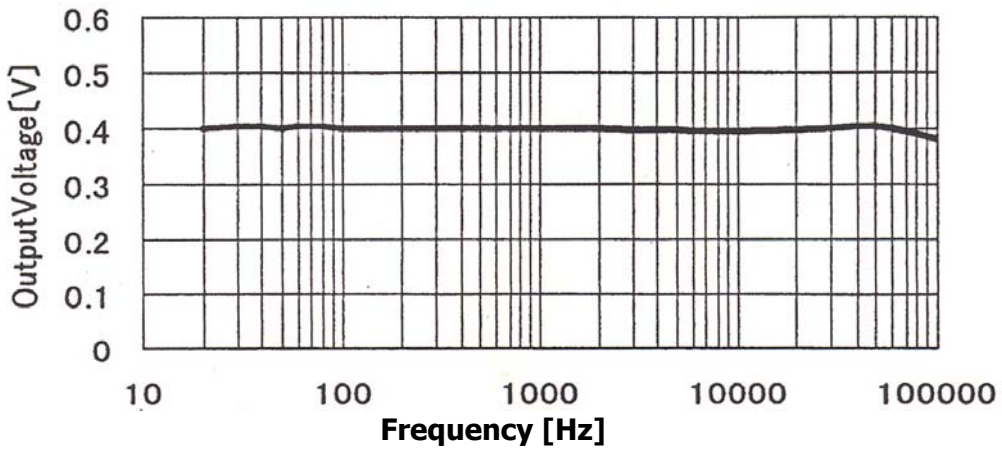
3. Pin Configuration

No.1	+15V
No.2	- 15V
No.3	Output
No.4	GND
No.5	Input (+)
No.6	Input (-)

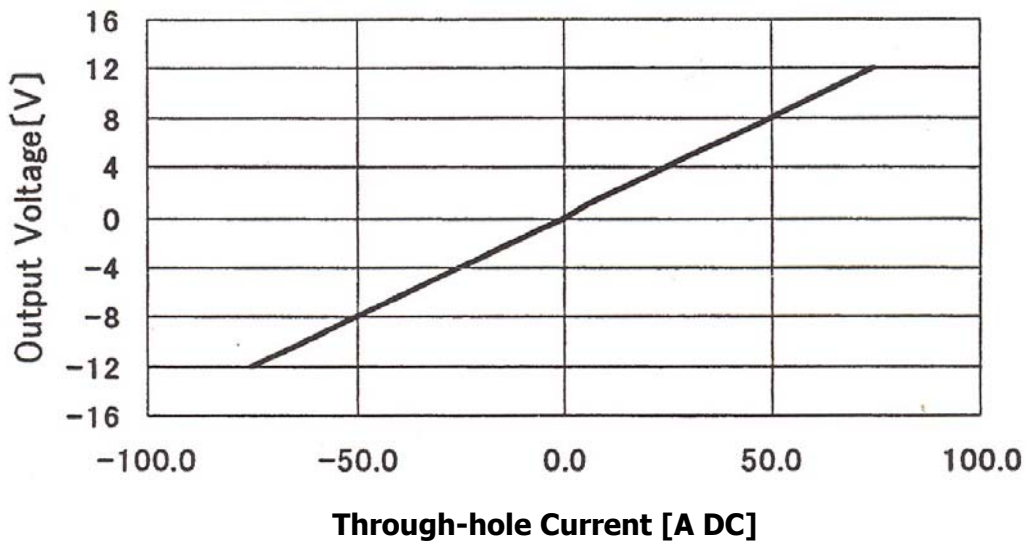
4. Specifications:

Continuous Rated Current	±25A
Non-saturated Max. Current	±75A
Output Voltage	±4V /Rated Current, ±12V/Max.Current
Residual Voltage	within ±30mV (at no load)
Noise Level	20mVp-p or less (at no load)
Output Accuracy/Linearity	within±1% Full Scale
Response time	3μ sec or less (at di/dt=FS/2μsec)
Output Voltage Temp.Coefficient	±0.1%/°C
Control Power Supply	±15V±5% (25mA Typ.) Split P/S
DC Resistance of Primary Winding	0.4mΩ
Max.Allowable Pulse Current	Rated Current x 10 times for 50msec
Dielectric Strength	AC2000V/1 min (Between Primary winding/Control terminals)
Insulation Resistance	≥DC500V/500MΩ (Between Primary winding/Control terminals)
Operating Temp.	-20°C~+75°C, ≤85%RH, No condensation
Storage Temp.	-30°C~+90°C, ≤85%, No condensation
Weight	7g

HPS-25-AP : Frequency Characteristics

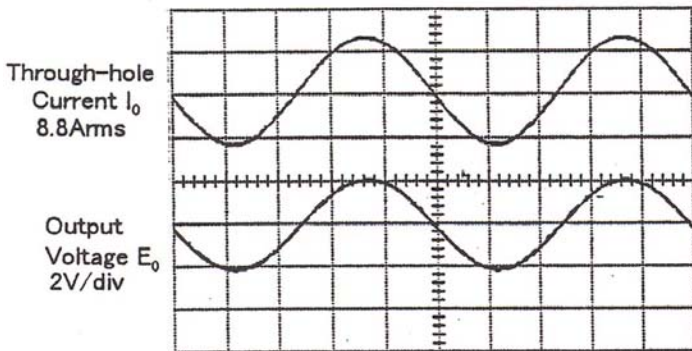


HPS-25-AP : Input-Output Characteristics



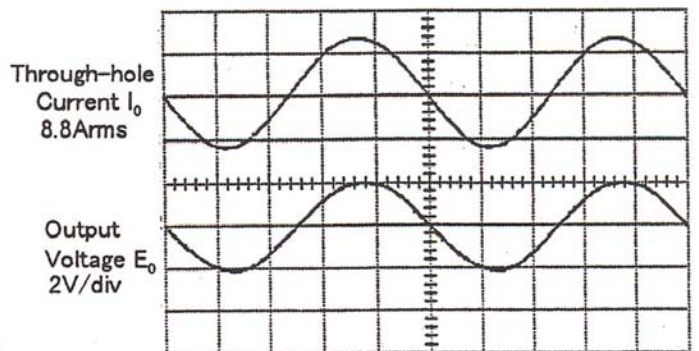
HPS-25-AP : Output Voltage Responsibility

[2KHz Sine Wave]



100 μ s/div

[20KHz Sine Wave]



10 μ s/div